



**ELECTRICAL CHARACTERISTICS (T<sub>a</sub> = 25 °C)**

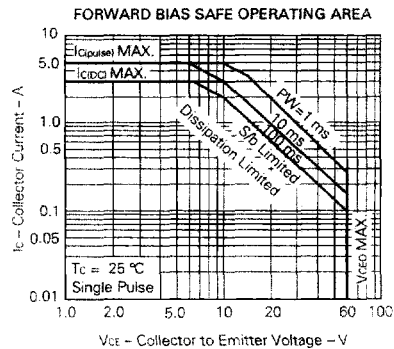
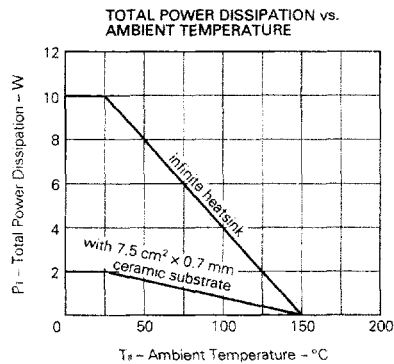
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Collector Cutoff Current	I <sub>CEO</sub>			10	μA	V <sub>CE</sub> = 60 V, I <sub>E</sub> = 0
Emitter Cutoff Current	I <sub>EB0</sub>			10	μA	V <sub>EB</sub> = 7.0 V, I <sub>C</sub> = 0
DC Current Gain	h <sub>FE1</sub> *	60				V <sub>CE</sub> = 2.0 V, I <sub>C</sub> = 0.2 A
DC Current Gain	h <sub>FE2</sub> *	100		400		V <sub>CE</sub> = 2.0 V, I <sub>C</sub> = 0.6 A
DC Current Gain	h <sub>FE3</sub> *	50				V <sub>CE</sub> = 2.0 V, I <sub>C</sub> = 2.0 A
Collector Saturation Voltage	V <sub>CE(sat)</sub> *		0.14	0.25	V	I <sub>C</sub> = 1.5 A, I <sub>E</sub> = 0.15 A
Base Saturation Voltage	V <sub>BE(sat)</sub> *		0.93	1.2	V	I <sub>C</sub> = 1.5 A, I <sub>B</sub> = 0.15 A
Gain Bandwidth Product	f <sub>T</sub>		120		MHz	V <sub>CE</sub> = 5.0 V, I <sub>E</sub> = -1.5 A
Output Capacitance	C <sub>ob</sub>		30		pF	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1.0 MHz
Turn-on Time	t <sub>on</sub>		0.15	0.5	μs	I <sub>C</sub> = 1 A, V <sub>CC</sub> = 10 V, R <sub>L</sub> = 10 Ω
Storage Time	t <sub>stg</sub>		0.75	2.0	μs	I <sub>B1</sub> = -I <sub>B2</sub> = 0.1 A
Fall Time	t <sub>f</sub>		0.2	0.5	μs	

\* Pulsed: PW ≤ 350 μs, Duty Cycle ≤ 2 %

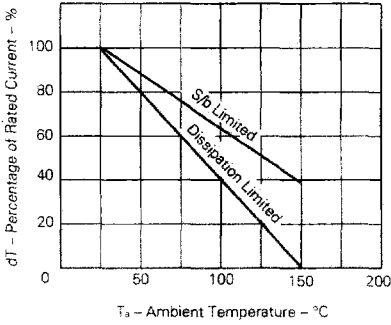
**h<sub>FE</sub> Classification**

MARKING	M	L	K
h <sub>FE2</sub>	100 to 200	160 to 320	200 to 400

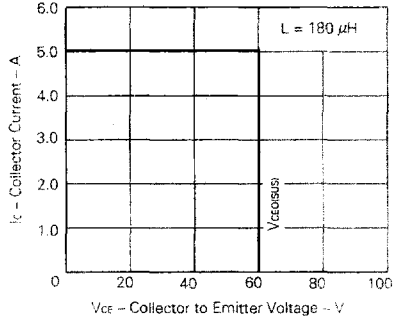
**TYPICAL CHARACTERISTICS (T<sub>a</sub> = 25 °C)**



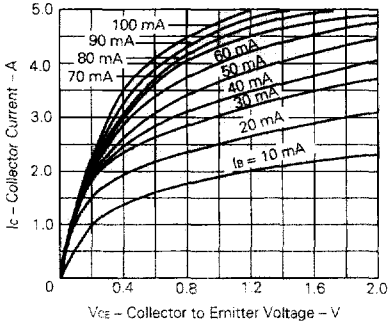
DERATING CURVE OF SAFE OPERATING AREA



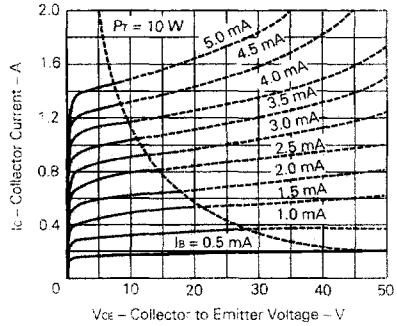
REVERSE BIAS SAFE OPERATING AREA



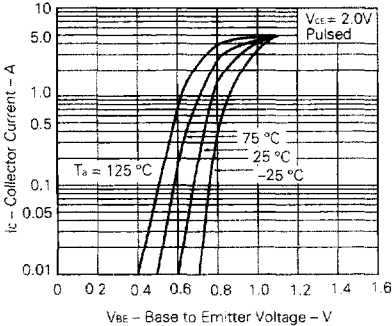
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE



DC CURRENT GAIN vs. COLLECTOR CURRENT

